Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
3.400 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
12.0 regulator voltage
Current Rating Per Characteristic:
400.00 milliamperes repetitive peak forward current
Power Rating Per Characteristic:
400.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius ambient air
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0